

3-MHz, LOW-POWER, LOW-NOISE, RRI/O, 1.8-V CMOS OPERATIONAL AMPLIFIER

Check for Samples: [OPA2314-EP](#)

FEATURES

- Low I_Q : 150 μ A/ch (max)
- Wide Supply Range: 1.8 V to 5.5 V
- Low Noise: 14 nV/ $\sqrt{\text{Hz}}$ at 1 kHz
- Gain Bandwidth: 3 MHz
- Low Input Bias Current: 0.2 pA
- Low Offset Voltage: 0.5 mV
- Unity-Gain Stable
- Internal RF/EMI Filter

APPLICATIONS

- Battery-Powered Instruments:
 - Consumer, Industrial, Medical
 - Notebooks, Portable Media Players
- Photodiode Amplifiers
- Active Filters
- Remote Sensing
- Wireless Metering
- Handheld Test Equipment

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly or Test Site
- One Fabrication Site
- Available in Extended (-40°C to 150°C) Temperature Range ⁽¹⁾
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability

(1) Additional temperature ranges available - contact factory

DESCRIPTION

The OPA2314 is a dual channel operational amplifier and represents a new generation of low-power, general-purpose CMOS amplifiers. Rail-to-rail input and output swings, low quiescent current (150 μ A typ at 5.0 V_S) combined with a wide bandwidth of 3 MHz, and very low noise (14 nV/ $\sqrt{\text{Hz}}$ at 1 kHz) make this family very attractive for a variety of battery-powered applications that require a good balance between cost and performance. The low input bias current supports applications with mega-ohm source impedances.

The robust design of the OPA2314 provides ease-of-use to the circuit designer: unity-gain stability with capacitive loads of up to 300 pF, an integrated RF/EMI rejection filter, no phase reversal in overdrive conditions, and high ESD protection (4-kV HBM).

This device is optimized for low-voltage operation as low as +1.8 V (± 0.9 V) and up to +5.5 V (± 2.75 V), and is specified over the full extended temperature range of -40°C to $+150^{\circ}\text{C}$.

The OPA2314 (dual) is offered in a DFN-8 package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE	ORDERABLE PART NUMBER	TOP-SIDE MARKING	VID NUMBER
-40°C to 150°C	DFN-8 – DRB	OPA2314ASDRBTEP	OUVS	V62/12626-01XE

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Over operating free-air temperature range, unless otherwise noted.

			UNIT
Supply voltage		7	V
Signal input terminals	Voltage ⁽²⁾	(V ₋) – 0.5 to (V ₊) + 0.5	V
	Current ⁽²⁾	±10	mA
Output short-circuit ⁽³⁾		Continuous	mA
Operating temperature, T _A		–40 to +150	°C
Storage temperature, T _{stg}		–65 to +150	°C
Junction temperature, T _J		+170	°C
ESD rating	Human body model (HBM)	4000	V
	Charged device model (CDM)	1000	V
	Machine model (MM)	200	V

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.
- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails should be current limited to 10 mA or less.
- (3) Short-circuit to ground, one amplifier per package.

ELECTRICAL CHARACTERISTICS: $V_S = +1.8\text{ V}$ to $+5.5\text{ V}$ ⁽¹⁾
Boldface limits apply over the specified temperature range: $T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$.

At $T_A = +25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

PARAMETERS		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFFSET VOLTAGE						
V _{OS}	Input offset voltage	V _{CM} = (V _S +) – 1.3 V		0.5	2.5	mV
	Over temperature	T _A = –40°C to +150°C			3.5	mV
dV _{OS} /dT	vs Temperature			1		μV/°C
PSRR	vs Power supply	V _{CM} = (V _S +) – 1.3 V	78	92		dB
	V _S = 5.5 V, (V _S –) – 0.2 V < V _{CM} < (V _S +) – 1.3 V	T _A = –40°C to +150°C	72			dB
	Channel separation, dc	At dc		10		μV/V
INPUT VOLTAGE RANGE						
V _{CM}	Common-mode voltage range		(V–) – 0.2	(V+) + 0.2		V
CMRR	Common-mode rejection ratio	V _S = 1.8 V, (V _S –) – 0.2 V < V _{CM} < (V _S +) – 1.3 V, T _A = –40°C to +150°C	68	86		dB
		V _S = 5.5 V, (V _S –) – 0.2 V < V _{CM} < (V _S +) – 1.3 V, T _A = –40°C to +150°C	71	90		dB
		V _S = 5.5 V, V _{CM} = –0.2 V to 5.7 V ⁽²⁾ , T _A = –40°C to +150°C	60			
INPUT BIAS CURRENT						
I _B	Input bias current			±0.2	±10	pA
	Over temperature	T _A = –40°C to +150°C			±2	nA
I _{OS}	Input offset current			±0.2	±10	pA
	Over temperature	T _A = –40°C to +150°C			±2	nA
NOISE						
	Input voltage noise (peak-to-peak)	f = 0.1 Hz to 10 Hz		5		μV _{PP}
e _n	Input voltage noise density	f = 10 kHz		13		nV/√Hz
		f = 1 kHz		14		nV/√Hz
i _n	Input current noise density	f = 1 kHz		5		fA/√Hz
INPUT CAPACITANCE						
C _{IN}	Differential	V _S = 5.0 V		1		pF
	Common-mode	V _S = 5.0 V		5		pF
OPEN-LOOP GAIN						
A _{OL}	Open-Loop Voltage Gain	V _S = 1.8 V, 0.2 V < V _O < (V+) – 0.2 V, R _L = 10 kΩ	90	115		dB
		V _S = 5.5 V, 0.2 V < V _O < (V+) – 0.2 V, R _L = 10 kΩ	100	128		dB
		V _S = 1.8 V, 0.5 V < V _O < (V+) – 0.5 V, R _L = 2 kΩ	90	100		dB
		V _S = 5.5 V, 0.5 V < V _O < (V+) – 0.5 V, R _L = 2 kΩ	94	110		dB
	Over temperature	V _S = 5.5 V, 0.2 V < V _O < (V+) – 0.2 V, R _L = 10 kΩ	90	110		dB
		V _S = 5.5 V, 0.5 V < V _O < (V+) – 0.2 V, R _L = 2 kΩ		100		dB
	Phase margin	V _S = 5.0 V, G = +1, R _L = 10 kΩ		65		deg

(1) Parameters with MIN and/or MAX specification limits are 100% production tested, unless otherwise noted.

(2) Limits are based on characterization and statistical analysis; not production tested.

ELECTRICAL CHARACTERISTICS: $V_S = +1.8\text{ V}$ to $+5.5\text{ V}^{(1)}$ (continued)**Boldface** limits apply over the specified temperature range: $T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$.At $T_A = +25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

PARAMETERS		TEST CONDITIONS	MIN	TYP	MAX	UNIT
FREQUENCY RESPONSE						
GBW	Gain-bandwidth product	V _S = 1.8 V, R _L = 10 kΩ, C _L = 10 pF		2.7		MHz
		V _S = 5.0 V, R _L = 10 kΩ, C _L = 10 pF		3		MHz
SR	Slew rate ⁽³⁾	V _S = 5.0 V, G = +1		1.5		V/μs
t _S	Settling time	To 0.1%, V _S = 5.0 V, 2-V step , G = +1		2.3		μs
		To 0.01%, V _S = 5.0V, 2-V step , G = +1		3.1		μs
	Overload recovery time	V _S = 5.0 V, V _{IN} × Gain > V _S		5.2		μs
THD+N	Total harmonic distortion + noise ⁽⁴⁾	V _S = 5.0 V, V _O = 1 V _{RMS} , G = +1, f = 1 kHz, R _L = 10 kΩ		0.001		%
OUTPUT						
V _O	Voltage output swing from supply rails	V _S = 1.8 V, R _L = 10 kΩ		5	15	mV
		V _S = 5.5 V, R _L = 10 kΩ		5	20	mV
		V _S = 1.8 V, R _L = 2 kΩ		15	30	mV
		V _S = 5.5 V, R _L = 2 kΩ		22	40	mV
Over temperature		V _S = 5.5 V, R _L = 10 kΩ			30	mV
		V _S = 5.5 V, R _L = 2 kΩ		60		mV
I _{SC}	Short-circuit current	V _S = 5.0 V		±20		mA
R _O	Open-loop output impedance	V _S = 5.5 V, f = 100 Hz		570		Ω
POWER SUPPLY						
V _S	Specified voltage range		1.8		5.5	V
I _Q	Quiescent current per amplifier	V _S = 1.8 V, I _O = 0 mA		130	180	μA
		V _S = 5.0 V, I _O = 0 mA		150	190	μA
Over temperature		V _S = 5.0 V, I _O = 0 mA			220	μA
	Power-on time	V _S = 0 V to 5 V, to 90% I _Q level		44		μs
TEMPERATURE						
	Specified range		−40		+150	°C
	Operating range		−40		+150	°C
	Storage range		−65		+150	°C

(3) Signifies the slower value of the positive or negative slew rate.

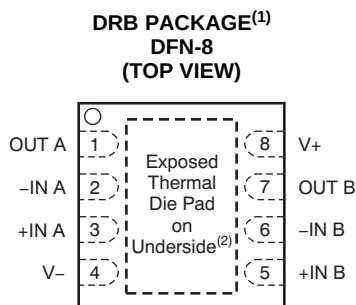
(4) Third-order filter; bandwidth = 80 kHz at -3 dB.

THERMAL INFORMATION

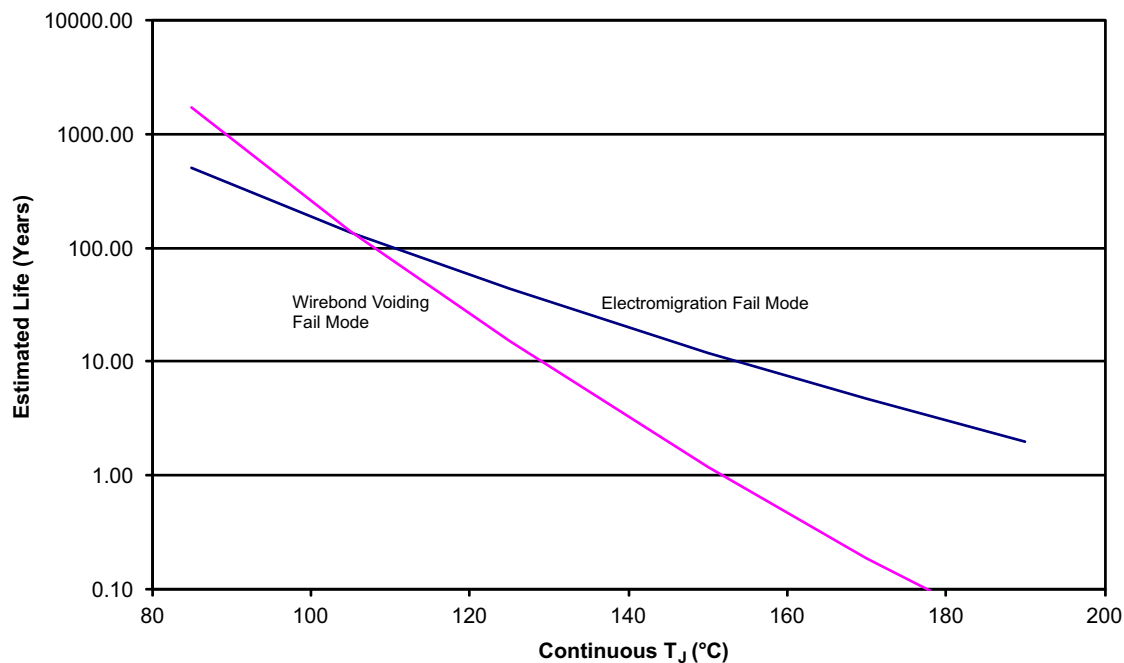
THERMAL METRIC ⁽¹⁾		OPA2314ASDRBTEP	UNITS
		DRB (DFN)	
		8 PINS	
θ_{JA}	Junction-to-ambient thermal resistance	53.8	$^\circ\text{C/W}$
$\theta_{JC(top)}$	Junction-to-case(top) thermal resistance	69.2	
θ_{JB}	Junction-to-board thermal resistance	20.1	
Ψ_{JT}	Junction-to-top characterization parameter	3.8	
Ψ_{JB}	Junction-to-board characterization parameter	20.0	
$\theta_{JC(bottom)}$	Junction-to-case(bottom) thermal resistance	11.6	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

PIN CONFIGURATIONS



- (1) Pitch: 0,65mm.
- (2) Connect thermal pad to V-. Pad size: 1,8mm × 1,5mm.



- (1) See datasheet for absolute maximum and minimum recommended operating conditions.
- (2) Silicon operating life design goal is 10 years at 105°C junction temperature (does not include package interconnect life).
- (3) Enhanced plastic product disclaimer applies.

Figure 1. OPA2314-EP Operating Life Derating Chart

TYPICAL CHARACTERISTICS

At $T_A = +25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

**OPEN-LOOP GAIN AND PHASE
vs FREQUENCY**

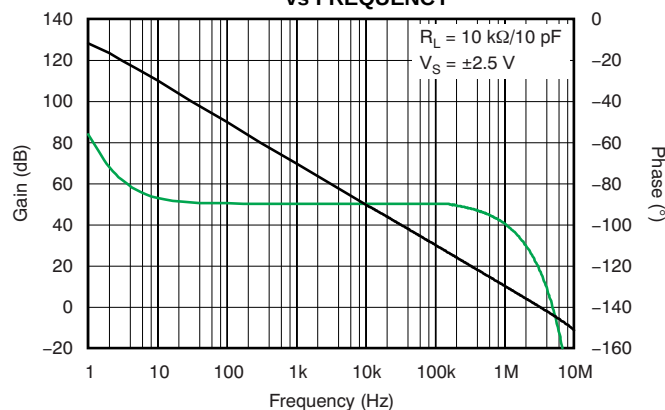


Figure 2.

**OPEN-LOOP GAIN
vs TEMPERATURE**

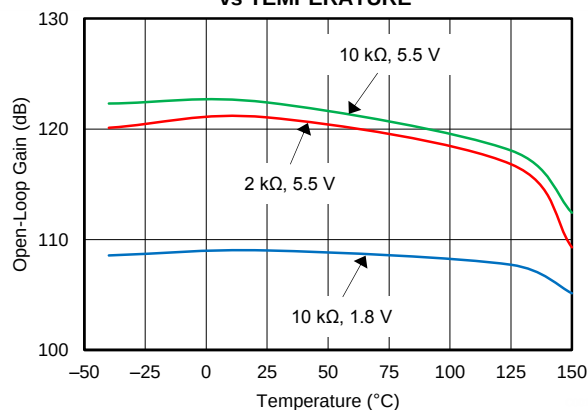


Figure 3.

**QUIESCENT CURRENT
vs SUPPLY**

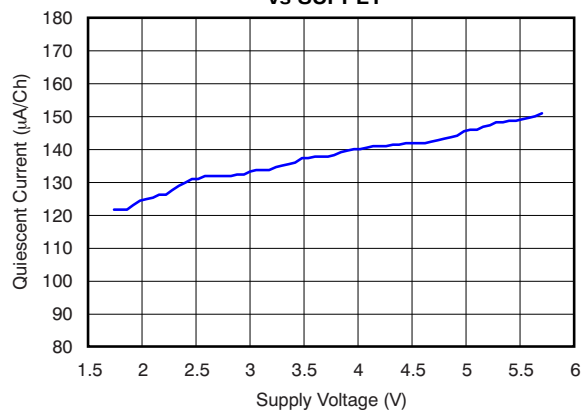


Figure 4.

**QUIESCENT CURRENT
vs TEMPERATURE**

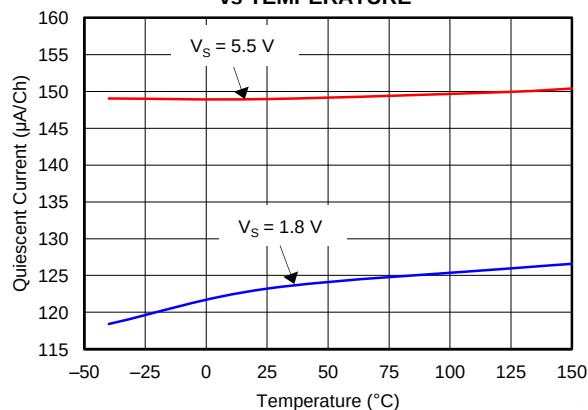


Figure 5.

OFFSET VOLTAGE PRODUCTION DISTRIBUTION

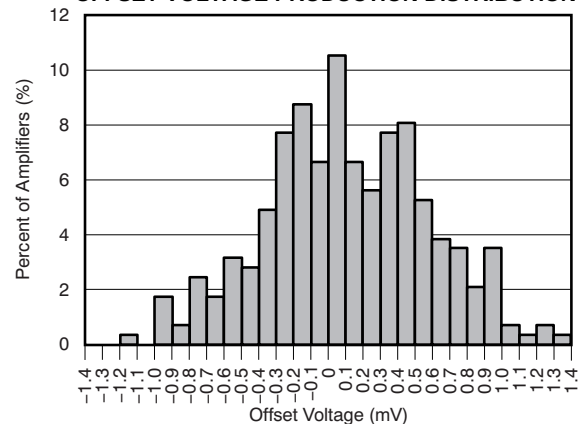


Figure 6.

OFFSET VOLTAGE DRIFT DISTRIBUTION

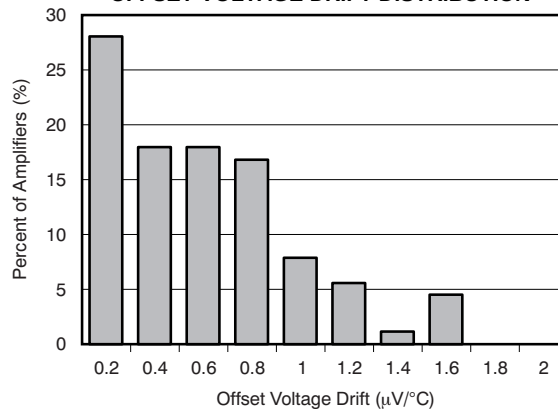


Figure 7.

TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

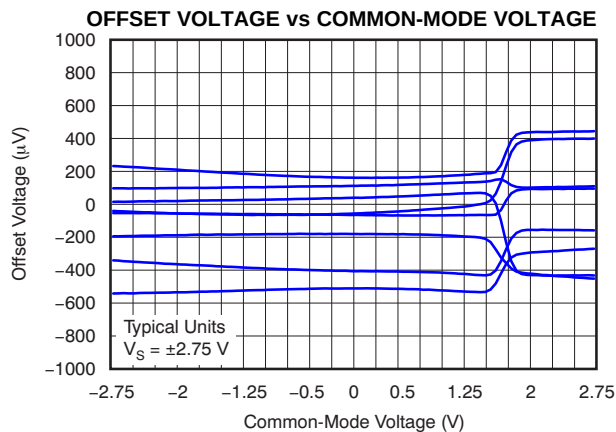


Figure 8.

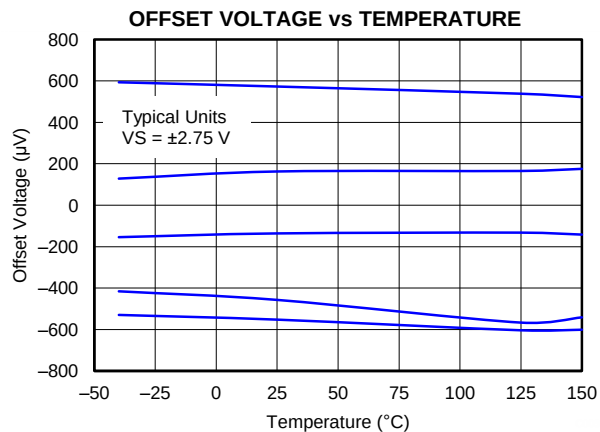


Figure 9.

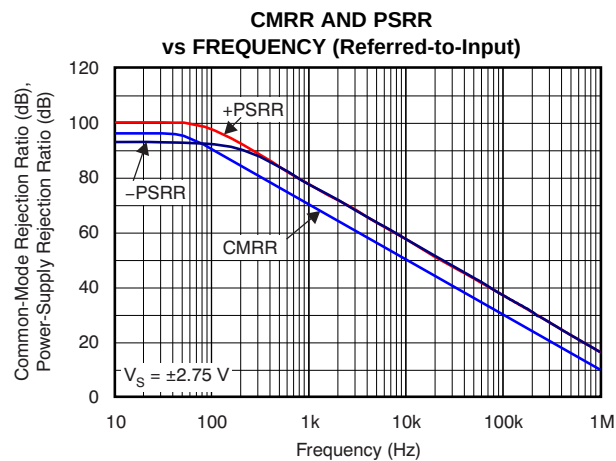


Figure 10.

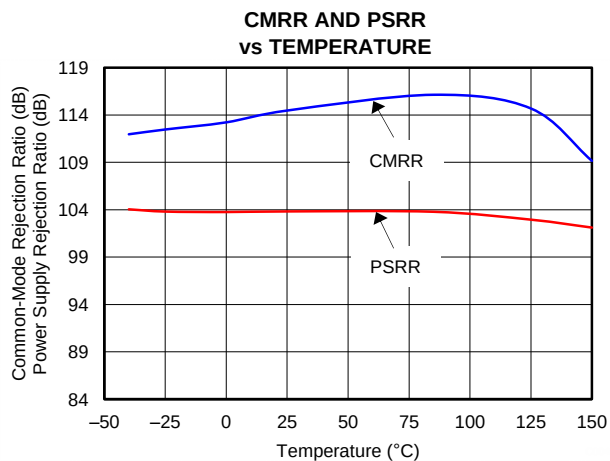


Figure 11.

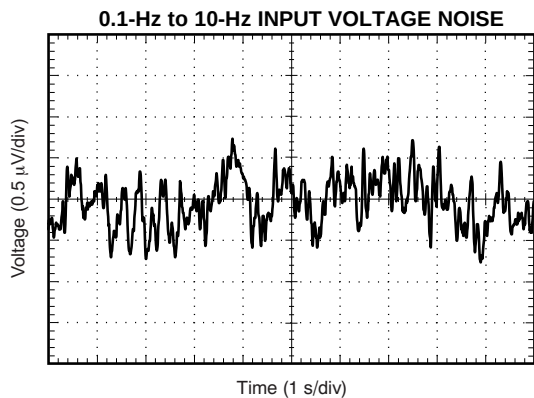


Figure 12.

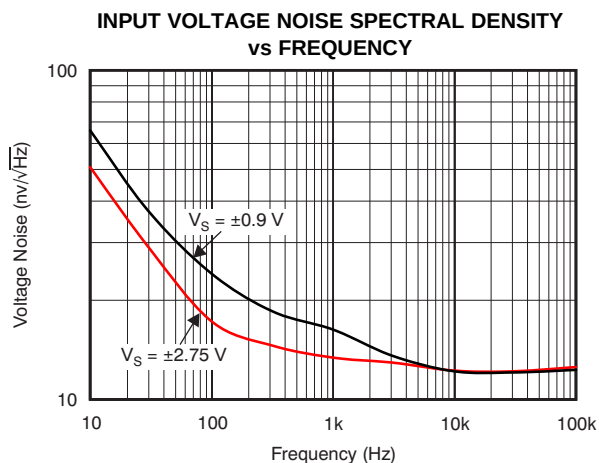


Figure 13.

TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

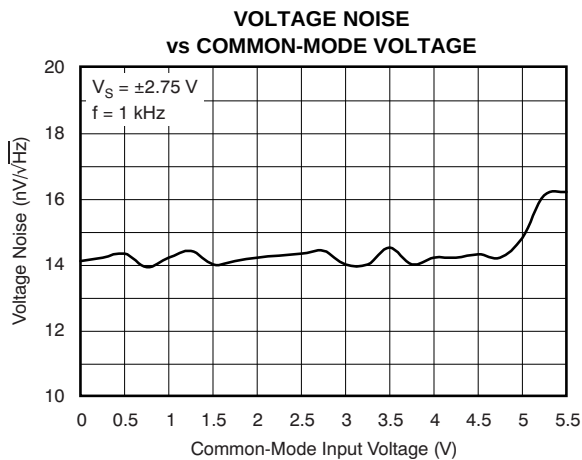


Figure 14.

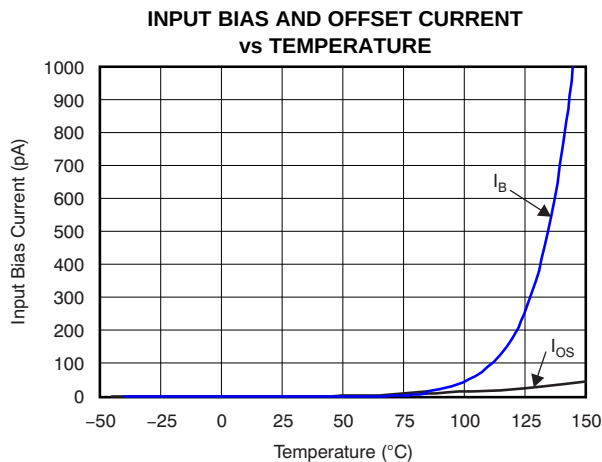


Figure 15.

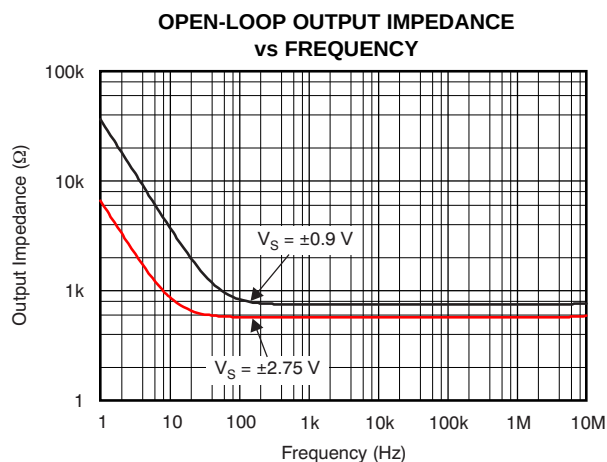


Figure 16.

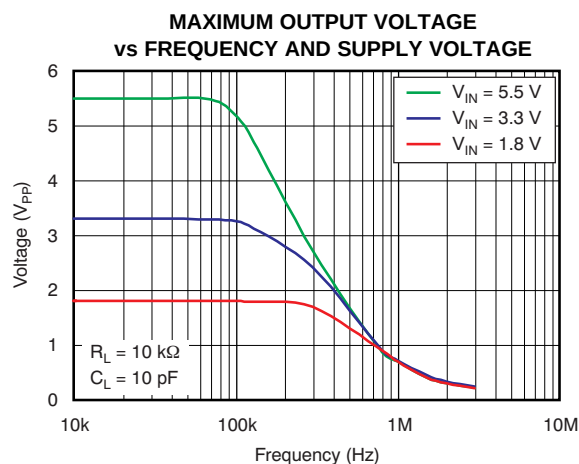


Figure 17.

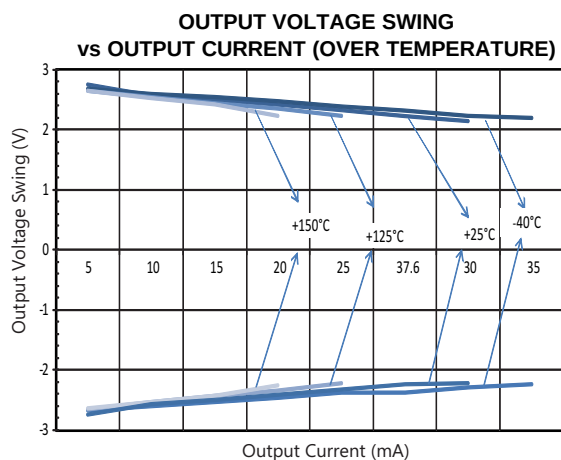


Figure 18.

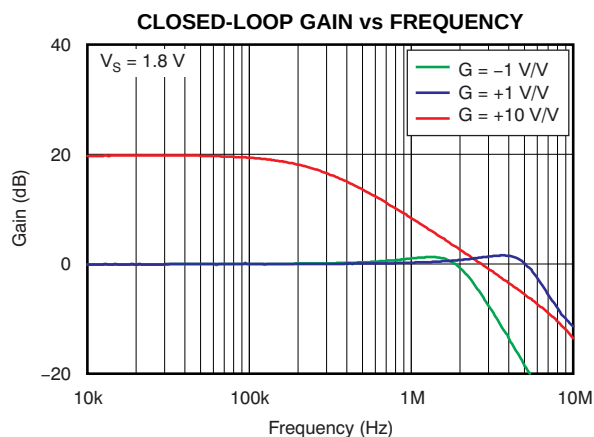


Figure 19.

TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

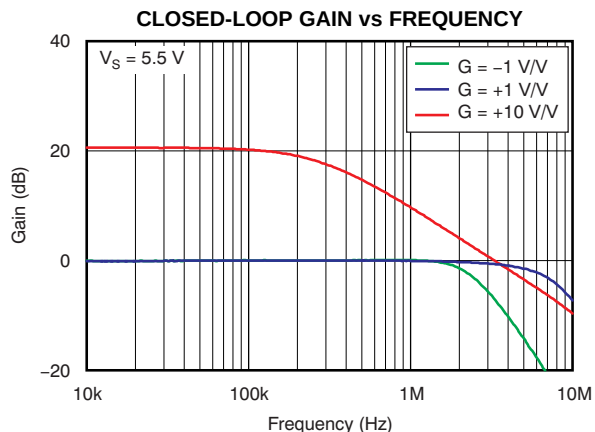


Figure 20.

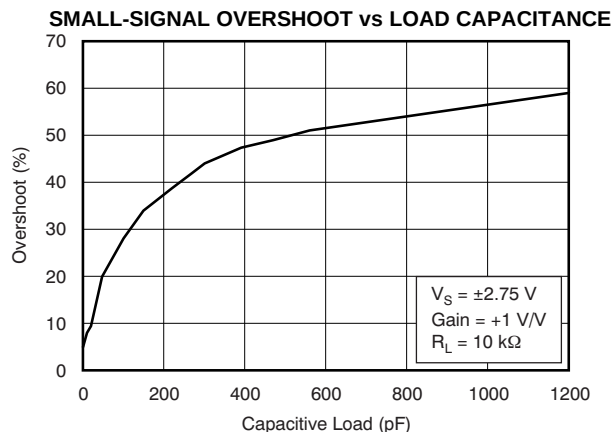


Figure 21.

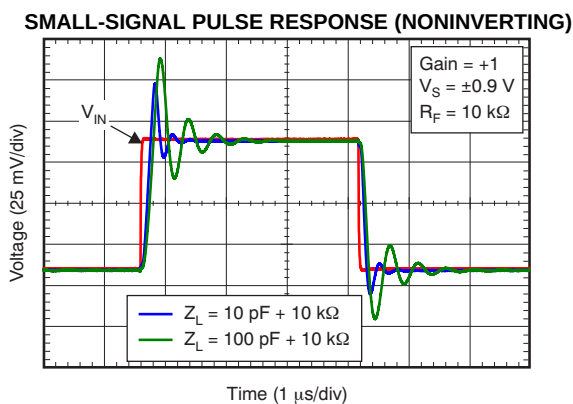


Figure 22.

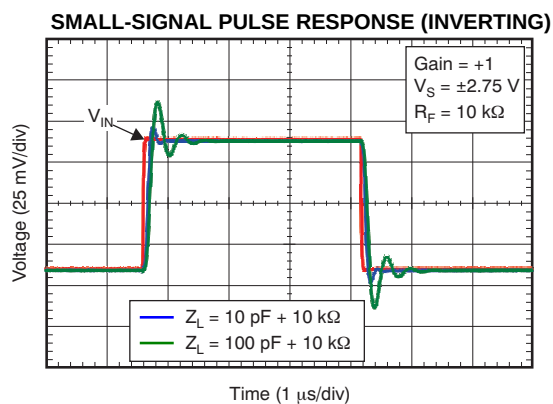


Figure 23.

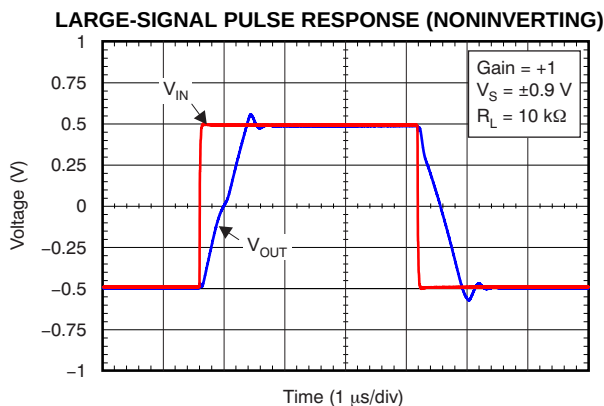


Figure 24.

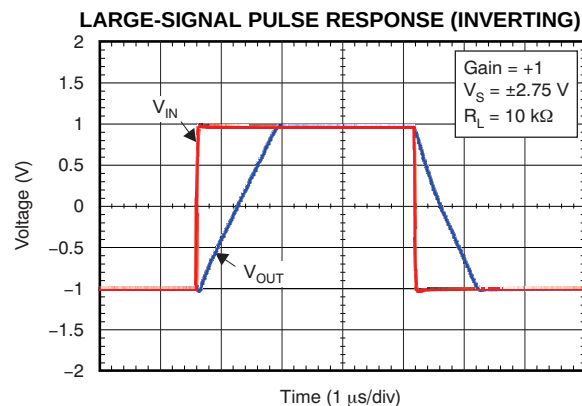


Figure 25.

TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

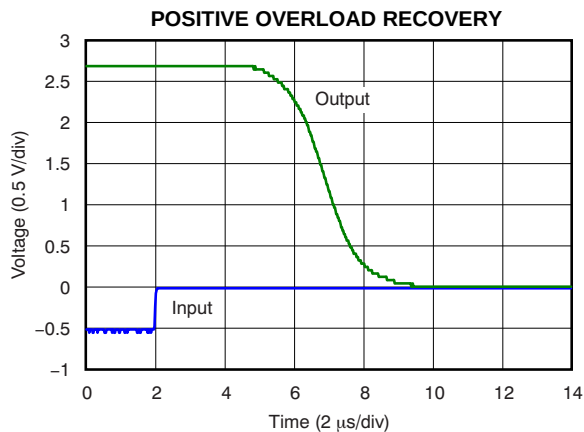


Figure 26.

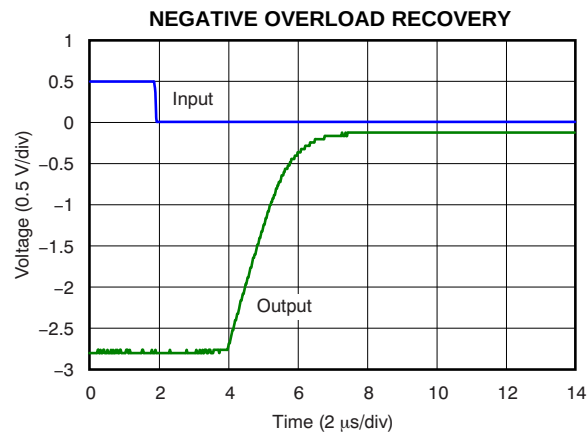


Figure 27.

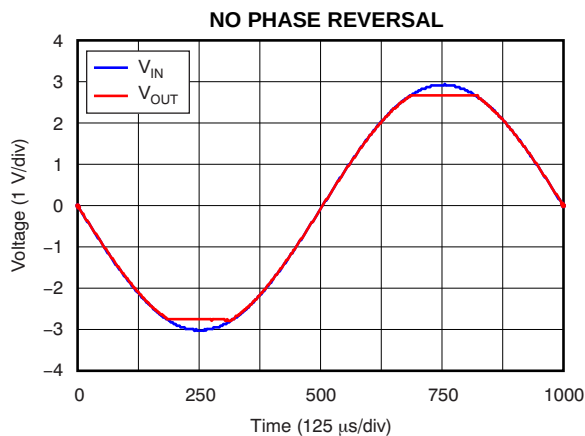


Figure 28.

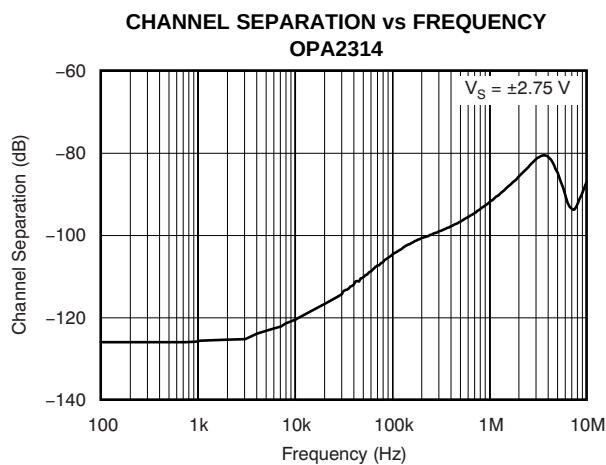


Figure 29.

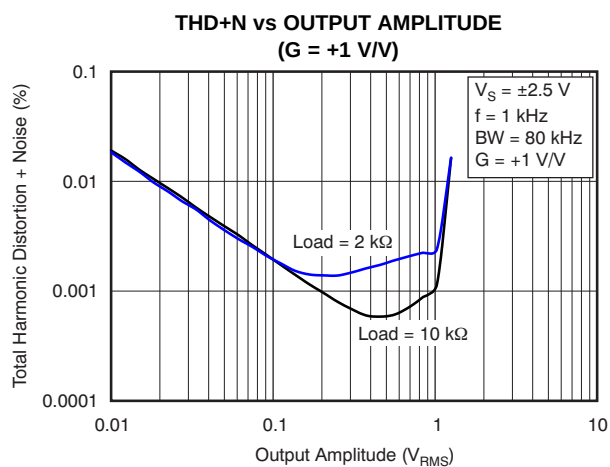


Figure 30.

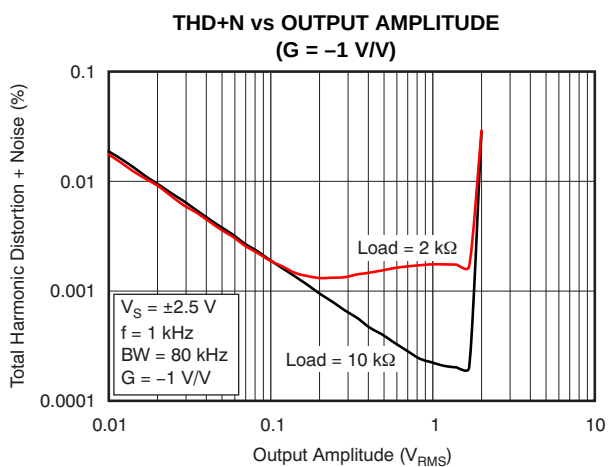


Figure 31.

TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

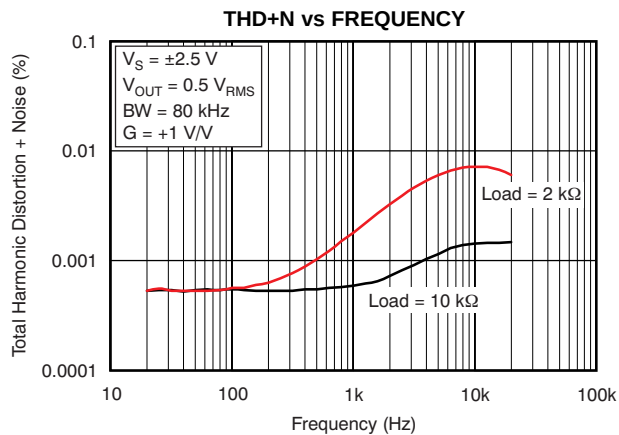


Figure 32.

ELECTROMAGNETIC INTERFERENCE REJECTION RATIO Referred to Noninverting Input (EMIRR IN+) vs FREQUENCY

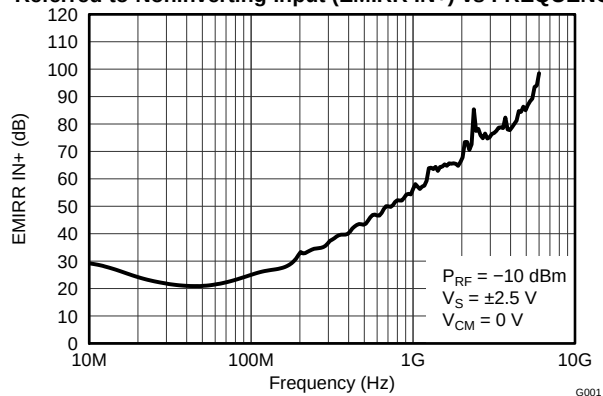


Figure 33.

APPLICATION INFORMATION

The OPA2314 is a low-power, rail-to-rail input/output operational amplifier specifically designed for portable applications. This device operates from 1.8 V to 5.5 V, is unity-gain stable, and suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving $\leq 10\text{-k}\Omega$ loads connected to any point between $V+$ and ground. The input common-mode voltage range includes both rails, and allows the OPA2314 to be used in virtually any single-supply application. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications, and makes them ideal for driving sampling analog-to-digital converters (ADCs).

The OPA2314 features 3-MHz bandwidth and 1.5-V/ μs slew rate with only 150- μA supply current per channel, providing good ac performance at very low power consumption. DC applications are also well served with a very low input noise voltage of 14 nV/ $\sqrt{\text{Hz}}$ at 1 kHz, low input bias current (0.2 pA), and an input offset voltage of 0.5 mV (typical).

Operating Voltage

The OPA2314 is fully specified and ensured for operation from +1.8 V to +5.5 V. In addition, many specifications apply from -40°C to $+150^{\circ}\text{C}$. Parameters that vary significantly with operating voltages or temperature are shown in the [Typical Characteristics](#) graphs. Power-supply pins should be bypassed with 0.01- μF ceramic capacitors.

Rail-to-Rail Input

The input common-mode voltage range of the OPA2314 extends 200 mV beyond the supply rails. This performance is achieved with a complementary input stage: an N-channel input differential pair in parallel with a P-channel differential pair, as shown in [Figure 34](#). The N-channel pair is active for input voltages close to the positive rail, typically $(V+) - 1.3\text{ V}$ to 200 mV above the positive supply, while the P-channel pair is on for inputs from 200 mV below the negative supply to approximately $(V+) - 1.3\text{ V}$. There is a small transition region, typically $(V+) - 1.4\text{ V}$ to $(V+) - 1.2\text{ V}$, in which both pairs are on. This 200-mV transition region can vary up to 300 mV with process variation. Thus, the transition region (both stages on) can range from $(V+) - 1.7\text{ V}$ to $(V+) - 1.5\text{ V}$ on the low end, up to $(V+) - 1.1\text{ V}$ to $(V+) - 0.9\text{ V}$ on the high end. Within this transition region, PSRR, CMRR, offset voltage, offset drift, and THD may be degraded compared to device operation outside this region.

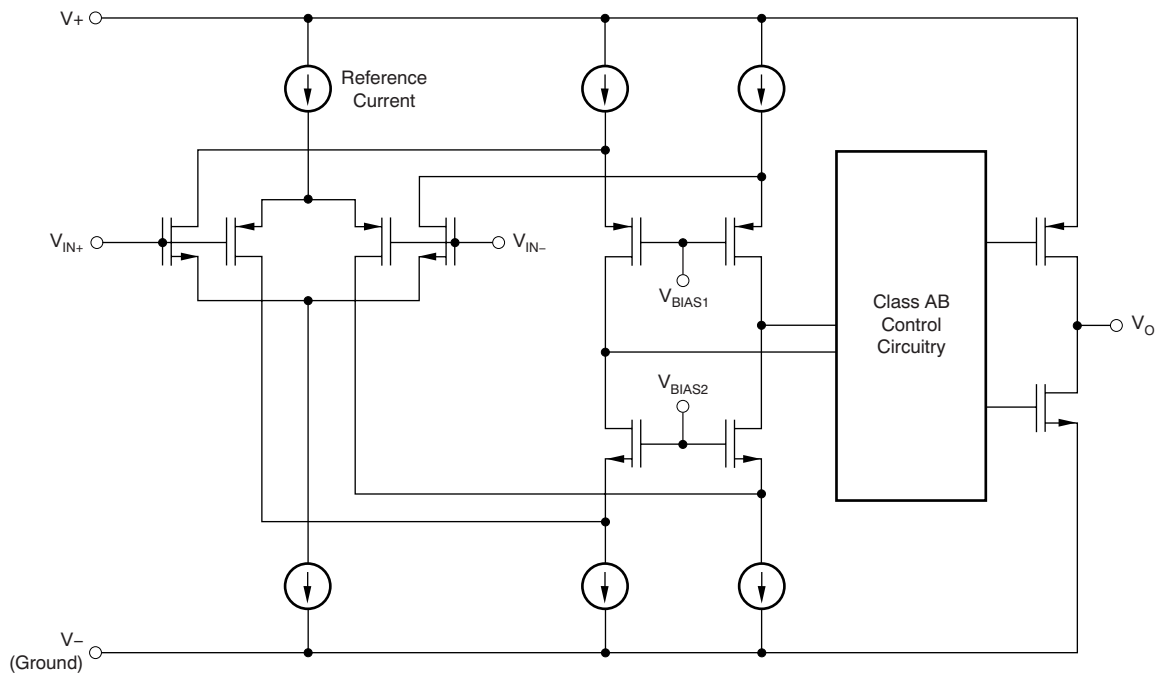


Figure 34. Simplified Schematic

Input and ESD Protection

The OPA2314 incorporates internal electrostatic discharge (ESD) protection circuits on all pins. In the case of input and output pins, this protection primarily consists of current steering diodes connected between the input and power-supply pins. These ESD protection diodes also provide in-circuit, input overdrive protection, as long as the current is limited to 10 mA as stated in the [Absolute Maximum Ratings](#). [Figure 35](#) shows how a series input resistor may be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and its value should be kept to a minimum in noise-sensitive applications.

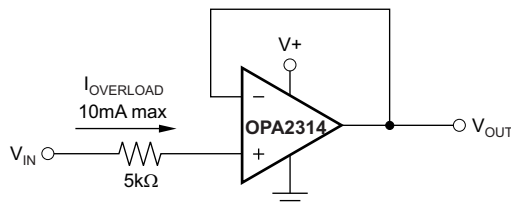


Figure 35. Input Current Protection

Common-Mode Rejection Ratio (CMRR)

CMRR for the OPA2314 is specified in several ways so the best match for a given application may be used; see the [Electrical Characteristics](#). First, the CMRR of the device in the common-mode range below the transition region [$V_{CM} < (V+) - 1.3\text{ V}$] is given. This specification is the best indicator of the capability of the device when the application requires use of one of the differential input pairs. Second, the CMRR over the entire common-mode range is specified at ($V_{CM} = -0.2\text{ V}$ to 5.7 V). This last value includes the variations seen through the transition region (see [Figure 8](#)).

EMI Susceptibility and Input Filtering

Operational amplifiers vary with regard to the susceptibility of the device to electromagnetic interference (EMI). If conducted EMI enters the op amp, the dc offset observed at the amplifier output may shift from its nominal value while EMI is present. This shift is a result of signal rectification associated with the internal semiconductor junctions. While all op amp pin functions can be affected by EMI, the signal input pins are likely to be the most susceptible. The OPA2314 operational amplifier incorporates an internal input low-pass filter that reduces the amplifiers response to EMI. Both common-mode and differential mode filtering are provided by this filter. The filter is designed for a cutoff frequency of approximately 80 MHz (–3 dB), with a roll-off of 20 dB per decade.

Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. The EMI rejection ratio (EMIRR) metric allows op amps to be directly compared by the EMI immunity. [Figure 33](#) shows the results of this testing on the OPAx314. Detailed information can also be found in the application report, *EMI Rejection Ratio of Operational Amplifiers* ([SBOA128](#)), available for download from the TI website.

Rail-to-Rail Output

Designed as a micro-power, low-noise operational amplifier, the OPA2314 delivers a robust output drive capability. A class AB output stage with common-source transistors is used to achieve full rail-to-rail output swing capability. For resistive loads up to 10 kΩ, the output swings typically to within 5 mV of either supply rail regardless of the power-supply voltage applied. Different load conditions change the ability of the amplifier to swing close to the rails, as can be seen in the typical characteristic graph, [Output Voltage Swing vs Output Current](#).

Capacitive Load and Stability

The OPA2314 is designed to be used in applications where driving a capacitive load is required. As with all op amps, there may be specific instances where the OPA2314 can become unstable. The particular op amp circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether or not an amplifier is stable in operation. An op amp in the unity-gain (+1-V/V) buffer configuration that drives a capacitive load exhibits a greater tendency to be unstable than an amplifier operated at a higher noise gain. The capacitive load, in conjunction with the op amp output resistance, creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases as the capacitive loading increases. When operating in the unity-gain configuration, the OPA2314 remains stable with a pure capacitive load up to approximately 1 nF. The equivalent series resistance (ESR) of some very large capacitors (C_L greater than 1 μ F) is sufficient to alter the phase characteristics in the feedback loop such that the amplifier remains stable. Increasing the amplifier closed-loop gain allows the amplifier to drive increasingly larger capacitance. This increased capability is evident when observing the overshoot response of the amplifier at higher voltage gains. See the typical characteristic graph, [Small-Signal Overshoot vs. Capacitive Load](#).

One technique for increasing the capacitive load drive capability of the amplifier operating in a unity-gain configuration is to insert a small resistor, typically 10 Ω to 20 Ω , in series with the output, as shown in [Figure 36](#). This resistor significantly reduces the overshoot and ringing associated with large capacitive loads. One possible problem with this technique, however, is that a voltage divider is created with the added series resistor and any resistor connected in parallel with the capacitive load. The voltage divider introduces a gain error at the output that reduces the output swing.

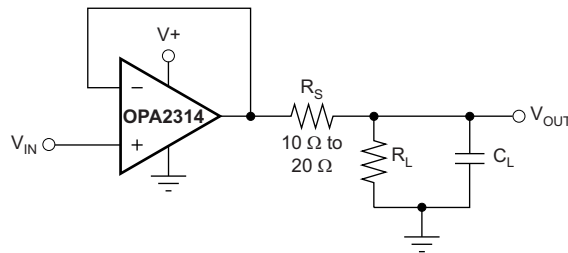


Figure 36. Improving Capacitive Load Drive

DFN Package

The OPA2314 (dual version) uses the DFN style package (also known as SON); this package is a QFN with contacts on only two sides of the package bottom. This leadless package maximizes printed circuit board (PCB) space and offers enhanced thermal and electrical characteristics through an exposed pad. One of the primary advantages of the DFN package is its low, 0.9-mm height. DFN packages are physically small, have a smaller routing area, improved thermal performance, reduced electrical parasitics, and use a pinout scheme that is consistent with other commonly-used packages, such as SO and MSOP. Additionally, the absence of external leads eliminates bent-lead issues.

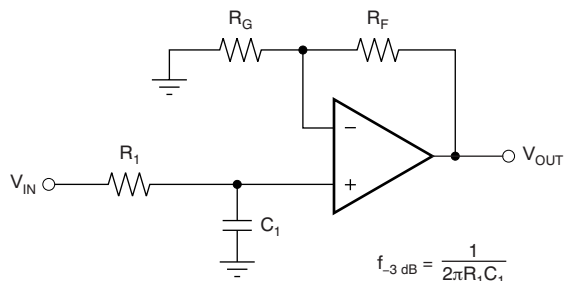
The DFN package can easily be mounted using standard PCB assembly techniques. See Application Note, [QFN/SON PCB Attachment \(SLUA271\)](#) and Application Report, [Quad Flatpack No-Lead Logic Packages \(SCBA017\)](#), both available for download from the TI website at www.ti.com.

NOTE: The exposed leadframe die pad on the bottom of the DFN package should be connected to the most negative potential (V-).

APPLICATION EXAMPLES

General Configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting terminal of the amplifier, as [Figure 37](#) illustrates.



$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1C_1}\right)$$

Figure 37. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task, as [Figure 38](#) shows. For best results, the amplifier should have a bandwidth that is eight to 10 times the filter frequency bandwidth. Failure to follow this guideline can result in phase shift of the amplifier.

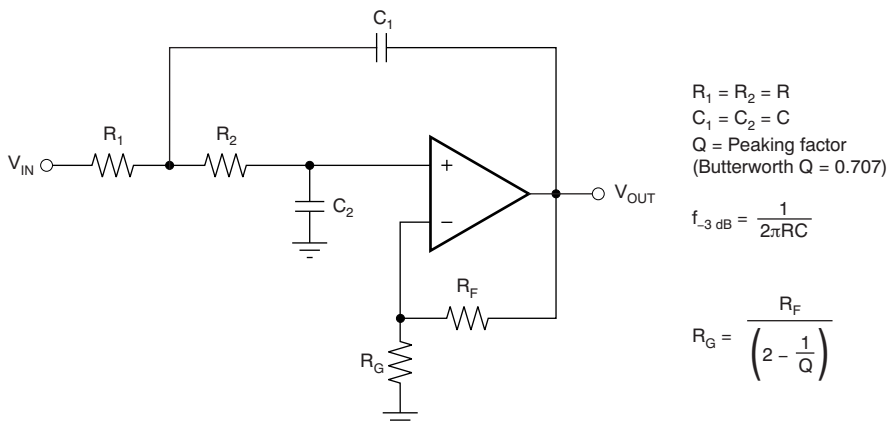


Figure 38. Two-Pole Low-Pass Sallen-Key Filter

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA2314ASDRBTEP	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	OUVS
OPA2314ASDRBTEP.A	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	OUVS
V62/12626-01XE	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	OUVS

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF OPA2314-EP :

- Catalog : [OPA2314](#)

- Automotive : [OPA2314-Q1](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

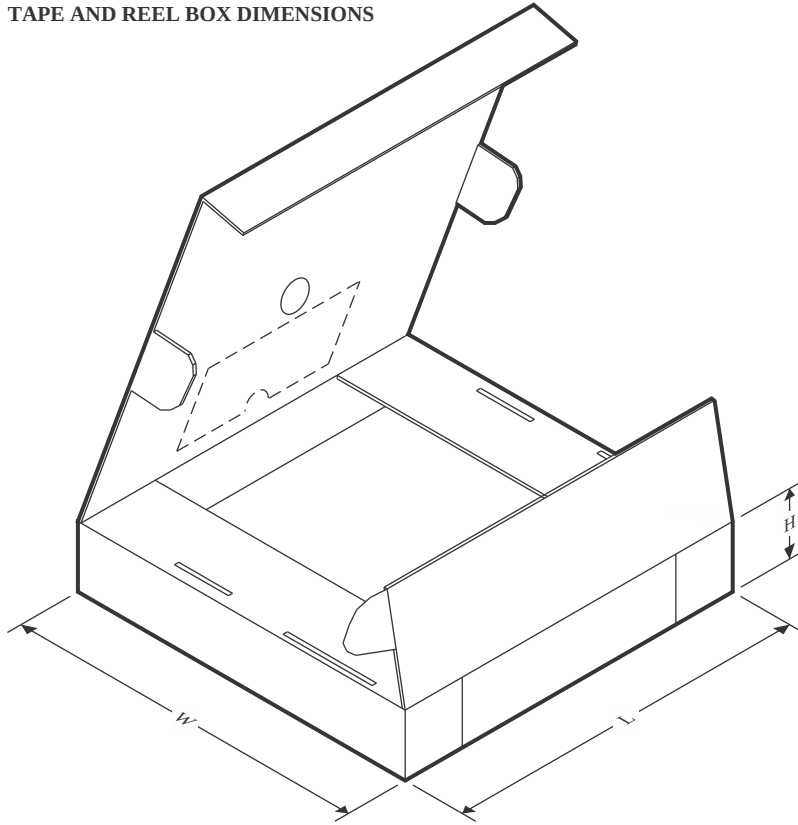
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2314ASDRBTEP	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

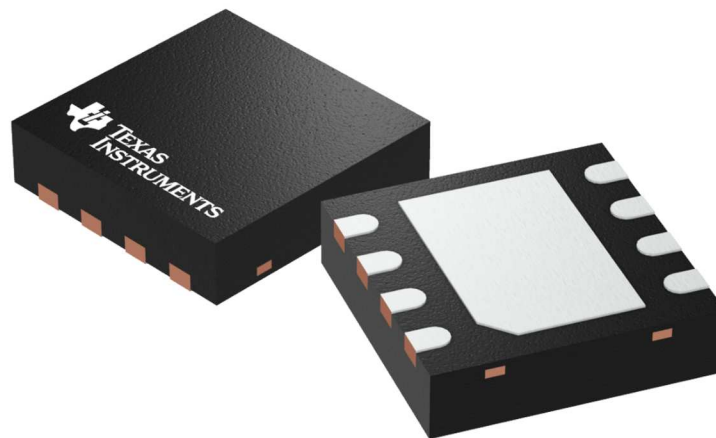
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2314ASDRBTPEP	SON	DRB	8	250	210.0	185.0	35.0

DRB 8

GENERIC PACKAGE VIEW

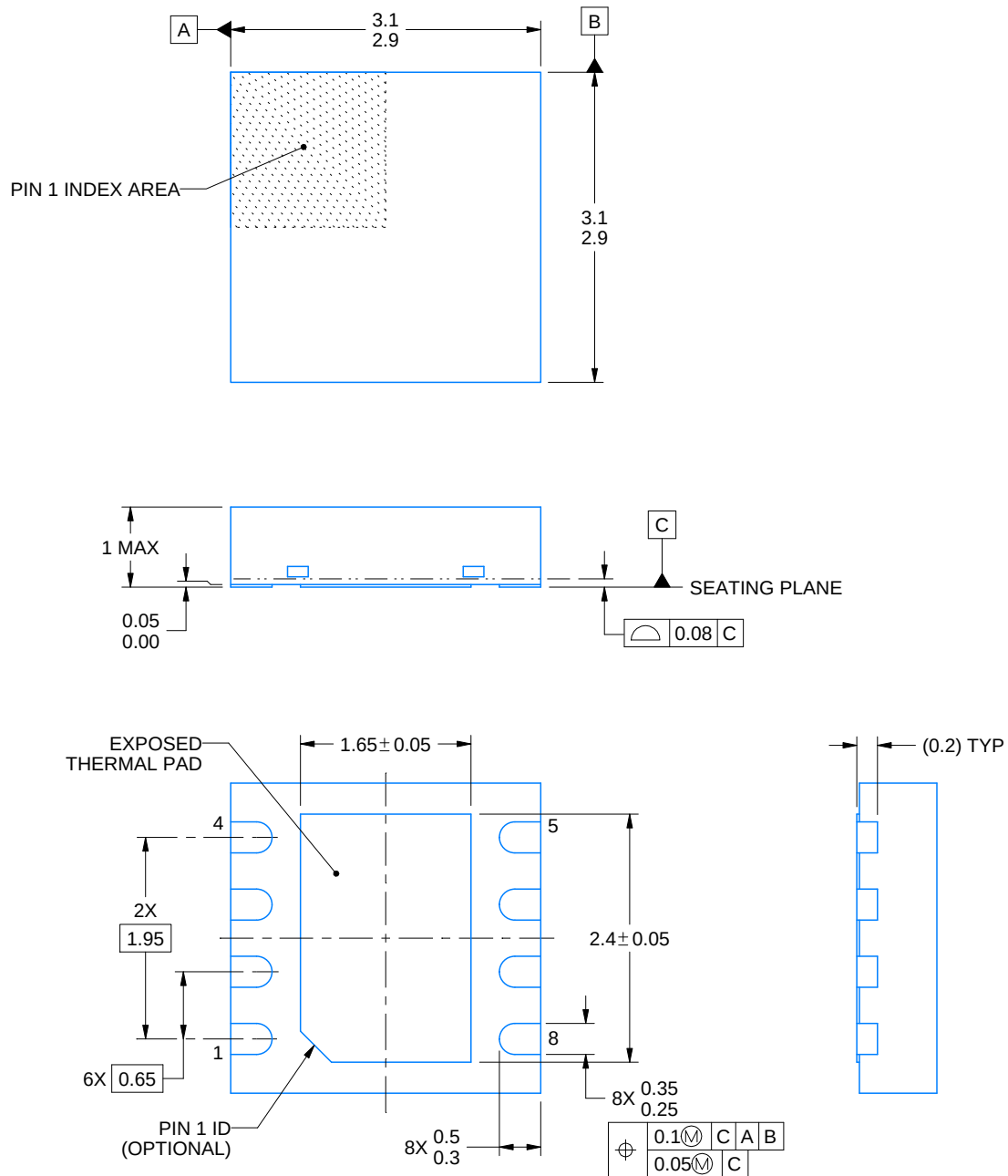
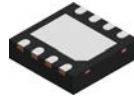
VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4203482/L



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NOTES:

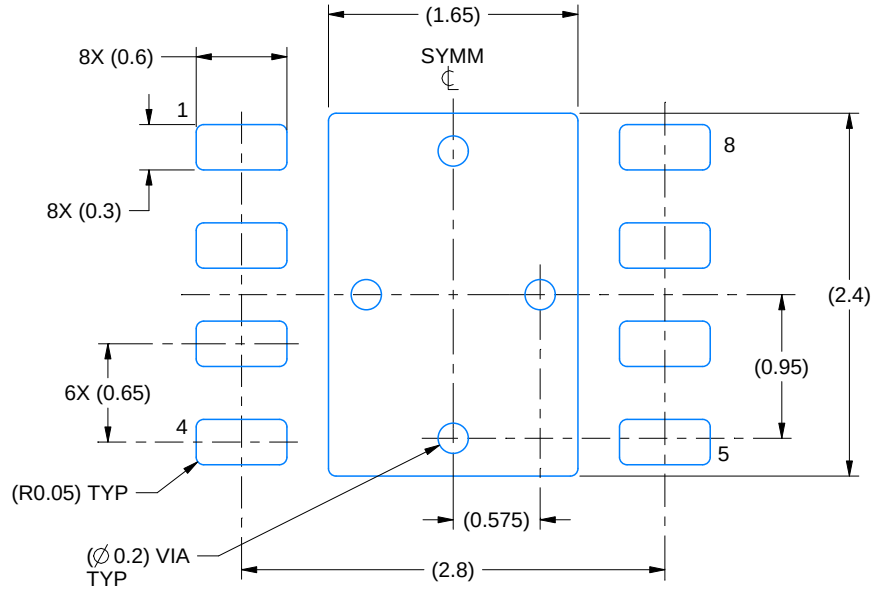
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

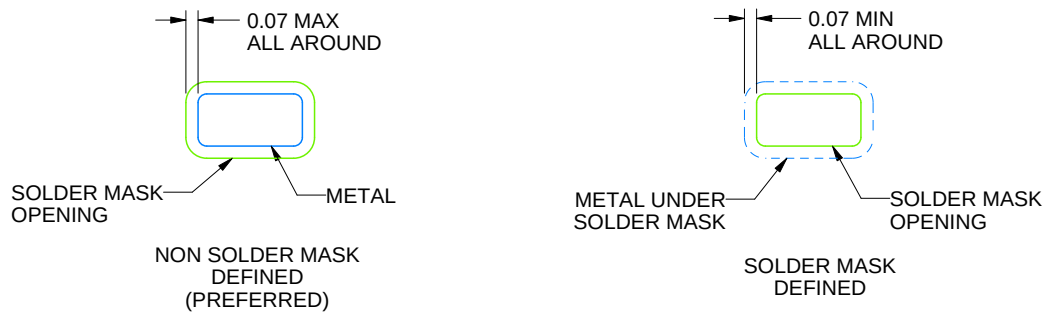
DRB0008B

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:20X



SOLDER MASK DETAILS

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NOTES: (continued)

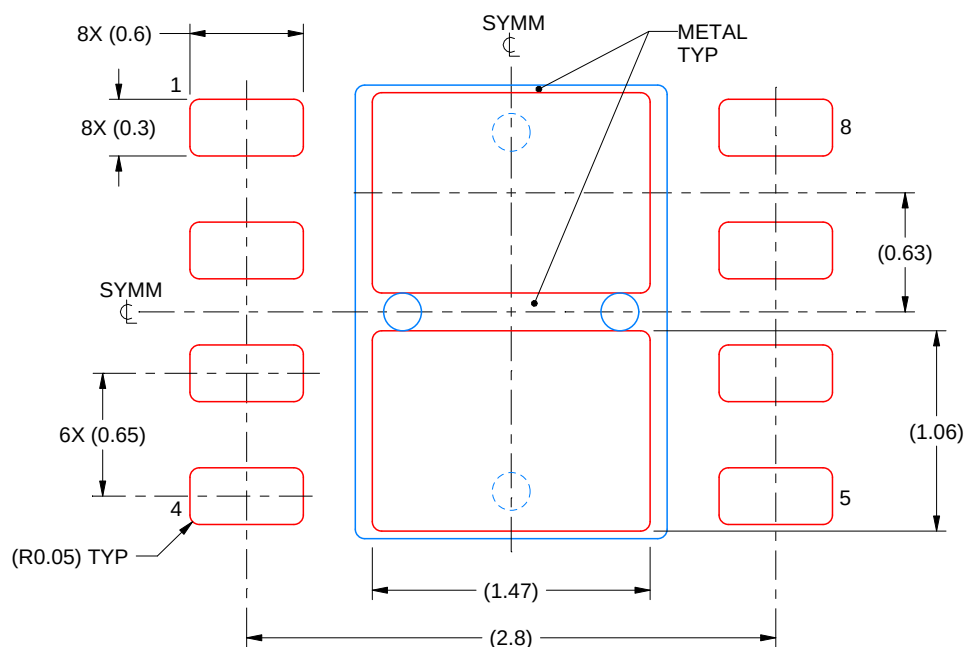
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DRB0008B

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
81% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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